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# RHRP1540, RHRP1560

#### Data Sheet

#### November 2013

## 15 A, 400 V - 600 V, Hyperfast Diode

The RHRP1540, RHRP1560 is a hyperfast diode with soft recovery characteristics. It has the half recovery time of ultrafast diodes and is silicon nitride passivated ionimplanted epitaxial planar construction. These devices are intended to be used as freewheeling/ clamping diodes and diodes in a variety of switching power supplies and other power switching applications. Their low stored charge and hyperfast soft recovery minimize ringing and electrical noise in many power switching circuits reducing power loss in the switching transistors.

### **Ordering Information**

PART NUMBER	PACKAGE	BRAND		
RHRP1540	TO-220AC-2L	RHRP1540		
RHRP1560	TO-220AC-2L	RHRP1560		

NOTE: When ordering, use the entire part number.

## Symbol



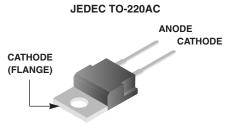
#### Features

- Hyperfast Recovery  $t_{rr}$  = 40 ns (@  $I_F$  = 15 A)
- Max Forward Voltage,  $V_F = 2.1 V$  (@  $T_C = 25^{\circ}C$ )
- 400 V, 600 V Reverse Voltage and High Reliability
- Avalanche Energy Rated
- RoHS Compliant

#### Applications

- · Switching Power Supplies
- · Power Switching Circuits
- General Purpose

#### Packaging



	RHRP1540	RHRP1560	UNIT
Peak Repetitive Reverse Voltage V <sub>RRM</sub>	400	600	V
Working Peak Reverse VoltageV <sub>RWM</sub>	400	600	V
DC Blocking VoltageV <sub>R</sub>	400	600	V
Average Rectified Forward Current	15	15	А
Repetitive Peak Surge CurrentI <sub>FRM</sub> (Square Wave, 20 kHz)	30	30	А
Nonrepetitive Peak Surge Current I <sub>FSM</sub> (Halfwave, 1 Phase, 60 Hz)	200	200	А
Maximum Power Dissipation	100	100	W
Avalanche Energy (See Figures 10 and 11)EAVL	20	20	mJ
Operating and Storage Temperature	-65 to 175	-65 to 175	°C

SYMBOL	TEST CONDITION	RHRP1540			RHRP1560			
		MIN	ТҮР	МАХ	MIN	ТҮР	МАХ	UNIT
V <sub>F</sub>	I <sub>F</sub> = 15 A	-	-	2.1	-	-	2.1	V
	I <sub>F</sub> = 15 A, T <sub>C</sub> = 150 <sup>o</sup> C	-	-	1.7	-	-	1.7	V
I <sub>R</sub>	V <sub>R</sub> = 400 V	-	-	100	-	-	-	μA
	V <sub>R</sub> = 600 V	-	-	-	-	-	100	μΑ
	$V_{R} = 400 \text{ V}, \text{ T}_{C} = 150^{\circ}\text{C}$	-	-	500	-	-	-	μΑ
	$V_{R} = 600 \text{ V}, \text{ T}_{C} = 150^{\circ}\text{C}$	-	-	-	-	-	500	μA
T <sub>rr</sub>	$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 100 \text{ A}/\mu\text{s}$	-	-	35	-	-	35	ns
	$I_F = 15 \text{ A}, \text{ d}I_F/\text{d}t = 100 \text{ A}/\mu\text{s}$	-	-	40	-	-	40	ns
t <sub>a</sub>	I <sub>F</sub> = 15 A, dI <sub>F</sub> /dt = 100 A/μs	-	20	-	-	20	-	ns
t <sub>b</sub>	I <sub>F</sub> = 15 A, dI <sub>F</sub> /dt = 100 A/μs	-	15	-	-	15	-	ns
Q <sub>rr</sub>	I <sub>F</sub> = 15 A, dI <sub>F</sub> /dt = 100 A/μs	-	40	-	-	40	-	nC
CJ	V <sub>R</sub> = 10 V, I <sub>F</sub> = 0 A	-	60	-	-	60	-	pF
R <sub>θJC</sub>		-	-	1.5	-	-	1.5	°C/V

#### **Electrical Specifications** $T_C = 25^{\circ}C$ , Unless Otherwise Specified

DEFINITIONS

 $V_F$  = Instantaneous forward voltage (pw = 300 µs, D = 2%).

 $I_R$  = Instantaneous reverse current .

 $T_{rr}$  = Reverse recovery time (See Figure 9), summation of  $t_a + t_b$ .

 $t_a$  = Time to reach peak reverse current (See Figure 9).

 $t_b$  = Time from peak  $I_{RM}$  to projected zero crossing of  $I_{RM}$  based on a straight line from peak  $I_{RM}$  through 25% of  $I_{RM}$  (See Figure 9).

Q<sub>rr</sub> = Reverse Recovery Change.

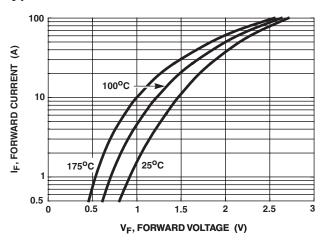
 $C_J$  = Junction Capacitance.

 $R_{\theta JC}$  = Thermal resistance junction to case.

pw = Pulse Width.

D = Duty Cycle.

#### **Typical Performance Curves**





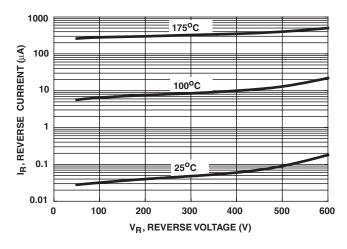


FIGURE 2. REVERSE CURRENT vs REVERSE VOLTAGE

### Typical Performance Curves (Continued)

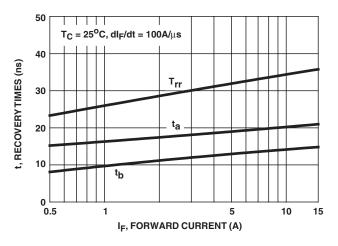


FIGURE 3. Trr, ta AND tb CURVES vs FORWARD CURRENT

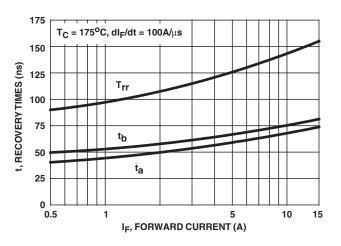


FIGURE 5. Trr, ta AND tb CURVES vs FORWARD CURRENT

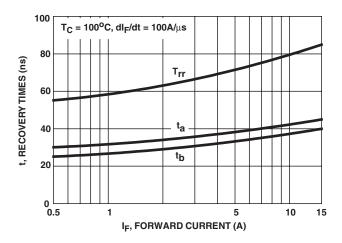


FIGURE 4. Trr, ta AND tb CURVES vs FORWARD CURRENT

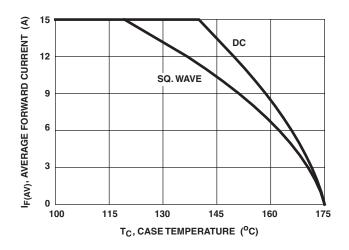


FIGURE 6. CURRENT DERATING CURVE

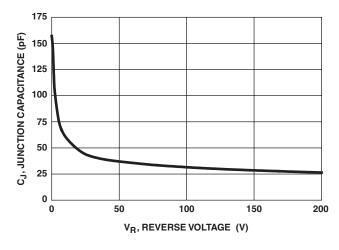
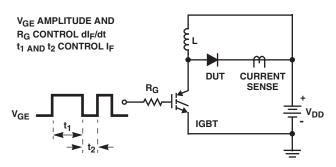


FIGURE 7. JUNCTION CAPACITANCE vs REVERSE VOLTAGE

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#### Test Circuits and Waveforms





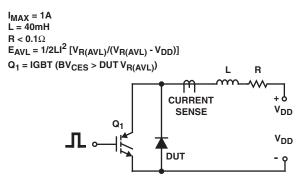


FIGURE 10. AVALANCHE ENERGY TEST CIRCUIT

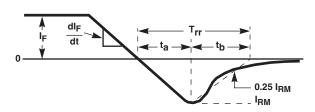


FIGURE 9.Ttrr WAVEFORMS AND DEFINITIONS

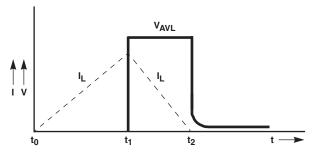


FIGURE 11. AVALANCHE CURRENT AND VOLTAGE WAVEFORMS

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